

HMC389LP4 / 389LP4E

v03.0507

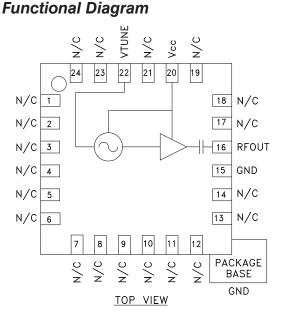


MMIC VCO w/ BUFFER AMPLIFIER, 3.35 - 3.55 GHz

Typical Applications

Low noise MMIC VCO w/Buffer Amplifier for:

- Wireless Local Loop (WLL)
- VSAT & Microwave Radio
- Test Equipment & Industrial Controls
- Military



Features

Pout: +4.7 dBm

Phase Noise: -112 dBc/Hz @100 KHz

No External Resonator Needed

Single Supply: 3V @ 41 mA

QFN Leadless SMT Package, 16 mm²

General Description

The HMC389LP4 & HMC389LP4E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs with integrated resonators, negative resistance devices, varactor diodes, and buffer amplifiers. Covering 3.35 to 3.55 GHz, the VCO's phase noise performance is excellent over temperature, shock, vibration and process due to the oscillator's monolithic structure. Power output is 4.7 dBm typical from a single supply of 3V @ 41mA. The voltage controlled oscillator is packaged in a low cost leadless QFN 4x4 mm surface mount package.

Electrical Specifications, $T_A = +25^{\circ}$ C, Vcc = +3V

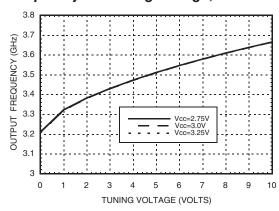
Parameter	Min.	Тур.	Max.	Units
Frequency Range	3.35 - 3.55		GHz	
Power Output	1.5	4.7		dBm
SSB Phase Noise @ 100 kHz Offset, Vtune= +5V @ RF Output		-112		dBc/Hz
Tune Voltage (Vtune)	0		10	V
Supply Current (Icc) (Vcc = +3.0V)		41		mA
Tune Port Leakage Current			10	μΑ
Output Return Loss		6		dB
Harmonics 2nd 3rd		-7 -16		dBc dBc
Pulling (into a 2.0:1 VSWR)		3.3		MHz pp
Pushing @ Vtune= +5V		-3		MHz/V
Frequency Drift Rate		0.4		MHz/°C



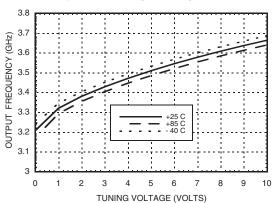


MMIC VCO w/ BUFFER AMPLIFIER, 3.35 - 3.55 GHz

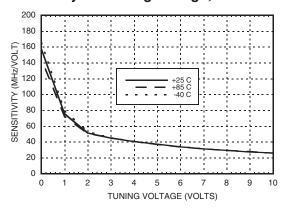
Frequency vs. Tuning Voltage, T= 25°C



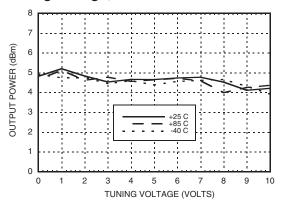
Frequency vs. Tuning Voltage, Vcc= +3V



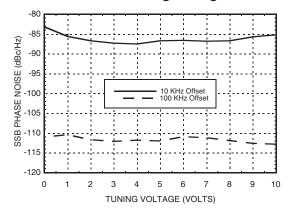
Sensitivity vs. Tuning Voltage, Vcc= +3V



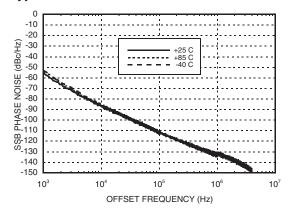
Output Power vs.
Tuning Voltage, Vcc= +3V



Phase Noise vs. Tuning Voltage



Typical SSB Phase Noise @ Vtune= +5V







MMIC VCO w/ BUFFER AMPLIFIER, 3.35 - 3.55 GHz

Absolute Maximum Ratings

Vcc	+3.5 Vdc
Vtune	0 to +11V
Channel Temperature	135 °C
Continuous Pdiss (T = 85°C) (derate 6.28 mW/°C above 85°C)	565 W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

Typical Supply Current vs. Vcc

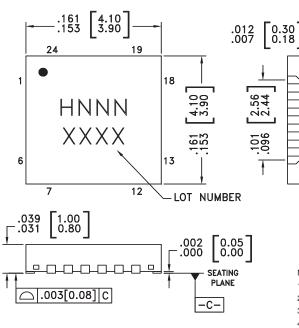
Vcc (V)	Icc (mA)	
2.75	35	
3.0	41	
3.25	46	

Note: VCO will operate over full voltage range shown above.

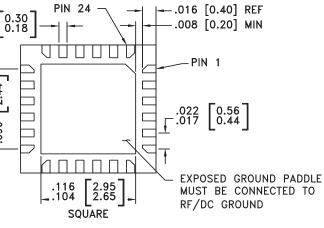


ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing



BOTTOM VIEW



NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
 PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOT FOR SUGGESTED LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC389LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H389 XXXX
HMC389LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H389 XXXX

- [1] Max peak reflow temperature of 235 $^{\circ}\text{C}$
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX





MMIC VCO w/ BUFFER AMPLIFIER, 3.35 - 3.55 GHz

Pin Descriptions

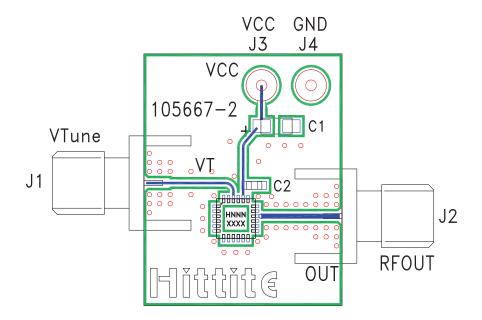
Pin Number	Function	Description	Interface Schematic
1- 14, 17 - 19, 21, 23, 24	N/C	No Connection	
15	GND	This pin must be connected to RF & DC ground.	GND =
16	RFOUT	RF output (AC coupled)	— —○ RFOUT
20	Vcc	Supply Voltage Vcc= 3V	Vcc O26pF
22	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance.	7.5nH 1500 VTUNEO C;= 10pF
	GND	Package bottom has an exposed metal paddle that must be RF & DC grounded.	○ GND =





MMIC VCO w/ BUFFER AMPLIFIER, 3.35 - 3.55 GHz

Evaluation PCB



List of Materials for Evaluation PCB 105706 [1]

Item	Description	
J1 - J2	PCB Mount SMA RF Connector	
J3 - J4	DC Pin	
C1	4.7 μF Tantalum Capacitor	
C2	10,000 pF Capacitor, 0603 Pkg.	
U1	HMC389LP4 / HMC389LP4E VCO	
PCB [2]	105667 Eval Board	

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

^[2] Circuit Board Material: Rogers 4350



v02.0805



Notes:

MMIC VCO w/ BUFFER AMPLIFIER, 3.35 - 3.55 GHz

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for VCO Oscillators category:

Click to view products by Analog Devices manufacturer:

Other Similar products are found below:

MAOC-009260-SMB003 MAOC-009261-PKG003 MAOC-009872-000000 MAOC-009264-PKG003 HMC384LP4ETR CVCO33CL-01100150 CVCO33CL-0415-0435 CVCO33CL-0750-0770 HMC1166LP5ETR HMC391LP4TR HMC1168LP5ETR MAOC-009260-PKG003

MAOC-009266-PKG003 HMC511LP5ETR HMC534LP5ETR HMC431LP4ETR HMC3587LP3BETR CVC055CC-1680-1680 CVCO33CL0125-0200 CVCO45CL-0100-0140 CVCO45CL-0421-0441 CRBV55BE-1930-1990 MAX2609EUT+T HMC1160LP5E HMC1164LP5E

HMC1166LP5E HMC1167LP5E HMC1168LP5E HMC587LC4BTR HMC732LC4B HMC358MS8GE HMC384LP4E HMC385LP4E

HMC388LP4E HMC390LP4E HMC391LP4 HMC391LP4E HMC398QS16GE HMC401QS16GE HMC416LP4E HMC429LP4E

HMC430LP4E HMC466LP4E HMC506LP4 HMC507LP5E HMC508LP5E HMC509LP5 HMC510LP5E HMC511LP5E HMC512LP5E